

測試報告

Test Report

智晶光電股份有限公司 WISECHIP SEMICONDUCTOR INC.

苗栗縣竹南鎮科北二路8號

8, KEBEI RD. 2, SCIENCE PARK, CHU-NAN, TAIWAN 350, R.O.C.

日期(Date): 2014/07/16 頁數(Page): 1 of 9

以下測試樣品係由申請廠商所提供及確認 (The following sample(s) was/were submitted and identified by/on behalf of the applicant as):

送樣廠商(Sample Submitted By) :

: 智晶光電股份有限公司 (WISECHIP SEMICONDUCTOR INC.)

樣品名稱(Sample Description)

OLE DISPLAY MODULE

樣品型號(Style/Item No.) 收件日期(Sample Receiving Date) : PANEL+COG

號碼(No.): CE/2014/71996

測試期間(Testing Period)

: 2014/07/09

2014/07/09 TO 2014/07/16

測試需求(Test Requested)

(1) 依據客户指定,進行鎘,鉛,汞,六價鉻,多溴聯苯,多溴聯苯醚測試. (As specified by client, to test Cadmium, Lead, Mercury, Cr(VI), PBBs, PBDEs contents in the submitted sample.)

(2) 依據客户指定,進行全氟辛酸、全氟辛烷磺酸、鹵素-氟、溴測試. (As specified by client, to test PFOA, PFOS, Halogen-Chlorine, Bromine contents in the submitted sample.)

測試方法(Test Method)

: 請見下一頁 (Please refer to next pages).

測試結果(Test Results)

: 請見下一頁 (Please refer to next pages).





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測試結果(Test Results)

測試部位(PART NAME) No.1: 整體混測 (MIXED ALL PARTS)

測試項目 (Test Items)	單位 (Unit)	測試方法 (Method)	方法偵測 極限値 (MDL)	結果 (Result) No.1
鎬 / Cadmium (Cd)	mg/kg	参考IEC 62321-5: 2013方法,以感應 耦合電漿原子發射光譜儀檢測./ With reference to IEC 62321-5: 2013 and performed by ICP-AES.	2	n.d.
鉛 / Lead (Pb)	mg/kg	參考IEC 62321-5: 2013方法,以感應 耦合電漿原子發射光譜儀檢測./ With reference to IEC 62321-5: 2013 and performed by ICP-AES.	2	5
汞 / Mercury (Hg)	mg/kg	參考IEC 62321-4: 2013方法,以感應 耦合電漿原子發射光譜儀檢測./ With reference to IEC 62321-4: 2013 and performed by ICP-AES.	2	n.d.
六價鉻 / Hexavalent Chromium Cr(VI)	mg/kg	参考IEC 62321: 2008方法,以UV-VIS 檢測. / With reference to IEC 62321: 2008 and performed by UV- VIS.	2	n.d.
鹵素(氣)/ Halogen-Chlorine (C1) (CAS No.: 22537-15-1)	mg/kg	参考BS EN 14582:2007, 以離子層析 儀分析. / With reference to BS EN 14582:2007. Analysis was performed by IC.	50	n.d.
鹵素(溴)/ Halogen-Bromine (Br) (CAS No.: 10097-32-2)	mg/kg	参考BS EN 14582:2007, 以離子層析 儀分析. / With reference to BS EN 14582:2007. Analysis was performed by IC.	50	n.d.



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測試項目 (Test Items)	單位 (Unit)	測試方法 (Method)	方法偵測 極限値 (MDL)	結果 (Result) No.1
全氟辛烷磺酸 / Perfluorooctane sulfonates (PFOS-Acid, Metal Salt, Amide)	mg/kg	參考US EPA 3550C: 2007方法, 以液相層析/質譜儀檢測. / With reference to US EPA 3550C: 2007.	10	n.d.
全氟辛酸 / PFOA (CAS No.: 335-67-1)	mg/kg	Analysis was performed by LC/MS.	10	n.d.
多溴聯苯總和 / Sum of PBBs			-	n.d.
一溴聯苯 / Monobromobiphenyl	mg/kg	參考IEC 62321: 2008方法, 以氣相層析/質譜儀檢測. / With reference to IEC 62321: 2008 and performed by GC/MS.	5	n.d.
二溴聯苯 / Dibromobiphenyl			5	n.d.
三溴聯苯 / Tribromobiphenyl			5	n.d.
四溴聯苯 / Tetrabromobiphenyl			5	n.d.
五溴聯苯 / Pentabromobiphenyl			5	n.d.
六溴聯苯 / Hexabromobiphenyl			5	n.d.
七溴聯苯 / Heptabromobiphenyl			5	n.d.
八溴聯苯 / Octabromobiphenyl			5	n.d.
九溴聯苯 / Nonabromobiphenyl			5	n.d.
十溴聯苯 / Decabromobiphenyl			5	n.d.
多溴聯苯醚總和 / Sum of PBDEs			-	n.d.
一溴聯苯醚 / Monobromodiphenyl ether			5	n.d.
二溴聯苯醚 / Dibromodiphenyl ether			5	n.d.
三溴聯苯醚 / Tribromodiphenyl ether			5	n.d.
四溴聯苯醚 / Tetrabromodiphenyl ether			5	n.d.
五溴聯苯醚 / Pentabromodiphenyl ether			5	n.d.
六溴聯苯醚 / Hexabromodiphenyl ether			5	n.d.
七溴聯苯醚 / Heptabromodiphenyl ether			5	n.d.
八溴聯苯醚 / Octabromodiphenyl ether			5	n.d.
九溴聯苯醚 / Nonabromodiphenyl ether			5	n.d.
十溴聯苯醚 / Decabromodiphenyl ether			5	n.d.

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備註(Note):

- 1. mg/kg = ppm ; 0.1wt% = 1000ppm
- 2. n.d. = Not Detected (未檢出)
- 3. MDL = Method Detection Limit (方法偵測極限值)
- 4. "-" = Not Regulated (無規格值)
- 5. 樣品的測試是基於申請人要求混合測試,報告中的混合測試結果不代表其中個别單一材質的含量. (The samples was/were analyzed on behalf of the applicant as mixing sample in one testing. The above results was/were only given as the informality value.)

PFOS参考資訊(Reference Information): 持久性有機污染物 POPs - (EU) 757/2010

PFOS濃度在物質或製備中不得超過0.001%(10ppm),在半成品、成品或零部件中不得超過0.1%(1000ppm),在紡織品或塗層材料中不得超過1 μ g/m²。(Outlawing PFOS as substances or preparations in concentrations above 0.001% (10ppm), in semi-finished products or articles or parts at a level above 0.1%(1000ppm), in textiles or other coated materials above 1μ g/m².)



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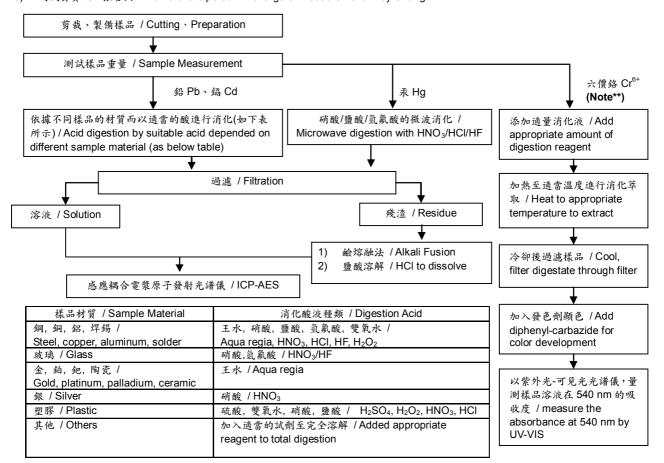
智晶光電股份有限公司

WISECHIP SEMICONDUCTOR INC.

苗栗縣竹南鎮科北二路8號

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- 1) 根據以下的流程圖之條件,樣品已完全溶解。(六價鉻測試方法除外) / These samples were dissolved totally by pre-conditioning method according to below flow chart. (Cr⁶⁺ test method excluded)
- 2) 测試人員:楊登偉 / Name of the person who made measurement: Climbgreat Yang
- 3) 測試負責人:張啓興 / Name of the person in charge of measurement: Troy Chang



Note**:(1) 針對非金屬材料加入鹼性消化液,加熱至 90~95℃萃取. / For non-metallic material, add alkaline digestion reagent and heat to 90~95℃.

(2) 針對金屬材料加入純水,加熱至沸騰萃取. / For metallic material, add pure water and heat to boiling.

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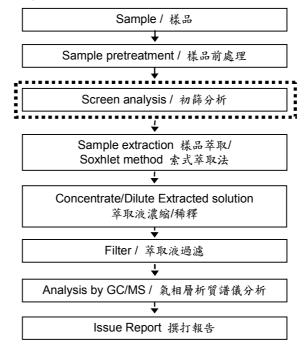
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多溴聯苯/多溴聯苯醚分析流程圖 / PBB/PBDE analytical FLOW CHART

- 測試人員: 翁賜彬 / Name of the person who made measurement: Roman Wong

確認程序 / Confirmation process - · - · ▶





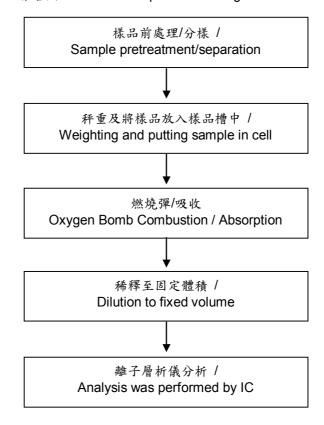
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鹵素分析流程圖 / Analytical flow chart of halogen content

- 測試人員:陳恩臻 / Name of the person who made measurement: Rita Chen
- 測試負責人:張啓興 / Name of the person in charge of measurement: Troy Chang





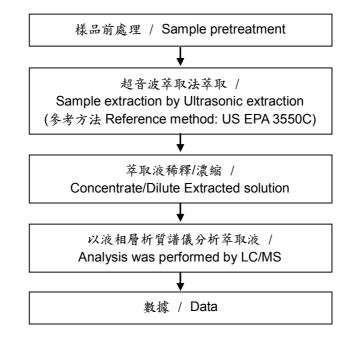
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全氟辛酸/全氟辛烷磺酸分析流程圖 / PFOA/PFOS analytical flow chart

- 測試人員:翁賜彬 / Name of the person who made measurement: Roman Wong
- 測試負責人:張啓興 / Name of the person in charge of measurement: Troy Chang





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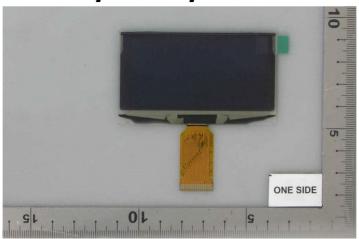
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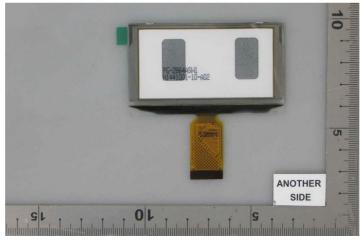
* 照片中如有箭頭標示,則表示為實際檢測之樣品/部位. *

(The tested sample / part is marked by an arrow if it's shown on the photo.)

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** 報告結尾(End of Report) **